

View Online at <https://aerobasegroup.com/nsn/5961-01-116-8763>

Inclosure Material:

Metal all transistor

Overall Length:

0.697 inches all transistor and 0.730 inches all transistor

Overall Height:

0.229 inches all transistor and 0.290 inches all transistor

Overall Width:

0.970 inches all transistor and 1.143 inches all transistor

Mounting Facility Quantity:

2 all transistor

Internal Configuration:

Junction contact all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Unthreaded hole all transistor

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

110.0 collector to base voltage/static/emitter open all transistor and 55.0 collector to emitter voltage/static/base open all transistor and 4.0 emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

15.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

300.0 watts small-signal input power, common-collector absolute all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction all transistor

Terminal Type And Quantity:

4 ribbon all transistor

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0